

## **Engineering Tripos Part IIA, 3B5: Semiconductor Engineering, 2019-20**

### **Module Leader**

[Dr H Joyce](#) [1]

### **Lecturers**

Dr H Joyce and Prof S Hofmann

### **Lab Leader**

Prof S Hofmann

### **Timing and Structure**

Michaelmas term. Weeks 1-4 (Dr H Joyce), weeks 5-8 (Prof S Hofmann). 16 lectures.

### **Aims**

The aims of the course are to:

- Provide a framework of basic semiconductor physics to demonstrate how this aids the design process and dictates the operation and performance limitations of devices in circuits and systems.

### **Objectives**

As specific objectives, by the end of the course students should be able to:

- Explain the concept of wave-particle duality especially with regard to electrons.
- Calculate allowed electron energy levels in single atoms from solutions of Schrodinger Equation, and be familiar with the concept of energy bands.
- Explain semiconductor behaviour in energy band and energy band concepts.
- Be familiar with the idea of the Fermi Level, and the formation of n and p type semiconductors by the deliberate addition of dopant atoms.
- Apply the continuity equation to different semiconductor problems.
- Explain the formation of p-n junctions, and be familiar with how current flow across the junction is limited by minority carrier flow.
- Know how p-n junction formation can be used in the design of JFETs and bipolar transistors.
- Compare and contrast the performance of JFET and Bipolar Transistors.
- Know how metal semiconductor junctions can be used in the design of MESFETs and HEMTs, and be able to compare operation with that of the JFET.
- Explain the contrast the operating modes of the MOSFET, and be familiar with how device design affects I-V characteristics.
- Understand how MOSFETs may be utilised as simple memory devices.

### **Content**

**Introduction to Quantum Mechanics and Basic Semiconductor Physics**

- Quantum mechanical basis for the physics of semiconductors: wave-particle duality, Schrodinger's equation,
- Fundamental semiconductor physics: E-k diagrams, energy bands, direct and indirect band gaps, density of states, Fermi level, intrinsic and extrinsic semiconductors, drift and diffusion, recombination and generation, continuity equation.

### Device Engineering and Introduction to Basic Junctions and Heterostructures

- p-n junctions band diagrams, junction in equilibrium, current flow in p-n junction, metal-semiconductor junctions, heterojunctions.
- The bipolar junction transistor (BJT), the heterojunction bipolar transistor (HBT), the junction field effect transistor (JFET), the metal semiconductor field effect transistor (MESFET), the high electron mobility transistor (HEMT) and the metal oxide semiconductor field effect transistor (MOSFET) - how they operate and I-V characteristics.

### Examples papers

Four examples papers are provided during the course, covering lectures 1-4, lectures 5-8, lectures 9-12 and lectures 13-16.

### Coursework

#### Schottky Barrier Diode

##### Learning objectives:

- Experimentally probe semiconductor engineering concepts related to theory given in lectures.
- Use oscillator circuit to investigate voltage dependence of the capacitance of a Schottky barrier diode and understand how this is a powerful technique for characterisation of semiconductor doping.
- Compare the current-voltage characteristics of Schottky and p-n diodes and explore deviations from ideal diode behaviour.

##### Practical information:

- Sessions will take place in the EIETL, during weeks 1-8 of Michaelmas term.
- This activity involves preliminary work (read and understand the lab handout).

##### Full Technical Report:

Students will have the option to submit a Full Technical Report.

### Booklists

Please see the [Booklist for Part IIA Courses](#) [2] for references for this module.

### Examination Guidelines

Please refer to [Form & conduct of the examinations](#) [3].

### UK-SPEC

This syllabus contributes to the following areas of the [UK-SPEC](#) [4] standard:

[Toggle display of UK-SPEC areas.](#)

## **GT1**

Develop transferable skills that will be of value in a wide range of situations. These are exemplified by the Qualifications and Curriculum Authority Higher Level Key Skills and include problem solving, communication, and working with others, as well as the effective use of general IT facilities and information retrieval skills. They also include planning self-learning and improving performance, as the foundation for lifelong learning/CPD.

## **IA1**

Apply appropriate quantitative science and engineering tools to the analysis of problems.

## **KU1**

Demonstrate knowledge and understanding of essential facts, concepts, theories and principles of their engineering discipline, and its underpinning science and mathematics.

## **KU2**

Have an appreciation of the wider multidisciplinary engineering context and its underlying principles.

## **E1**

Ability to use fundamental knowledge to investigate new and emerging technologies.

## **E2**

Ability to extract data pertinent to an unfamiliar problem, and apply its solution using computer based engineering tools when appropriate.

## **E3**

Ability to apply mathematical and computer based models for solving problems in engineering, and the ability to assess the limitations of particular cases.

## **P1**

A thorough understanding of current practice and its limitations and some appreciation of likely new developments.

## **P3**

Understanding of contexts in which engineering knowledge can be applied (e.g. operations and management, technology, development, etc).

## **US1**

A comprehensive understanding of the scientific principles of own specialisation and related disciplines.

## **US2**

A comprehensive knowledge and understanding of mathematical and computer models relevant to the engineering discipline, and an appreciation of their limitations.

**Source URL (modified on 10-06-20):** <https://teaching19-20.eng.cam.ac.uk/content/engineering-tripos-part-iiia-3b5-semiconductor-engineering-2019-20>

#### **Links**

[1] <mailto:hjj28@eng.cam.ac.uk>

[2] <https://www.vle.cam.ac.uk/mod/book/view.php?id=364091&chapterid=46331>

[3] <https://teaching19-20.eng.cam.ac.uk/content/form-conduct-examinations>

[4] <https://teaching19-20.eng.cam.ac.uk/content/uk-spec>